





#### 17.5V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

#### **Features**

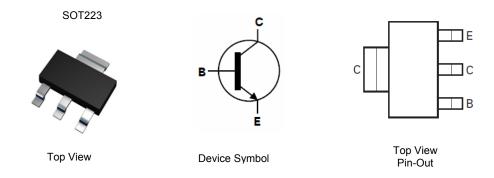
- BV<sub>CEO</sub> > 17.5V
- BV<sub>CES</sub> > 50V
- I<sub>C</sub> = 5A High Continuous Collector Current
- I<sub>CM</sub> = 20A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> <45mV @ 500mA</li>
- R<sub>SAT</sub> = 50mΩ @ 5A for a Low Equivalent On-Resistance
- h<sub>FE</sub> Specified up to 20A for a High Gain Hold-Up
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (approximate)

### **Applications**

- Solenoid, Relay and Actuator Drivers
- DC Modules
- Motor Control



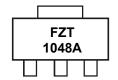
### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT1048ATA	FZT1048A	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



FZT1048A = Product Type Marking Code





#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	17.5	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	5	Α
Peak Pulse Current	I <sub>CM</sub>	20	Α
Base Current	I <sub>B</sub>	500	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Rower Dissipation	(Note 6)	Ь	2.0	W	
Power Dissipation	(Note 7)	$P_{D}$	1.6		
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Resistance, Junction to Ambient	(Note 6)	Б	62.5	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ hetaJA}$	78.1		
	(Note 8)		104	1	
Thermal Resistance Junction to Lead (Note 9)		$R_{ hetaJL}$	10.9		
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C		

## ESD Ratings (Note 10)

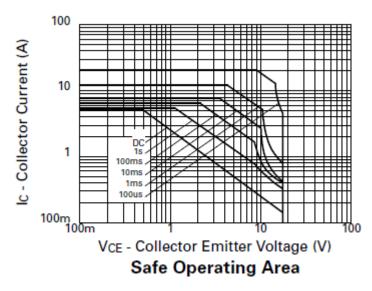
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

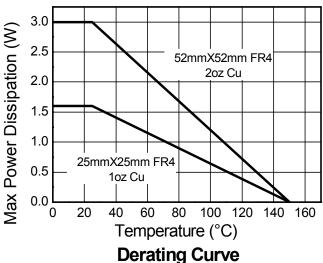
Notes:

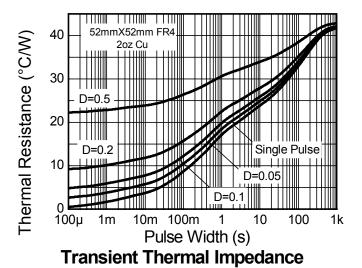
- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a s still air conditions whilst operating in a steady-state.
  Same as note (5), except the device is mounted on 25mm x 25mm 2oz copper.
  Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
  Same as note (5), except the device is mounted on minimum recommended pad layout.
  Thermal resistance from junction to solder-point (at the end of the collector lead).
  Refer to JEDEC specification JESD22-A114 and JESD22-A115.

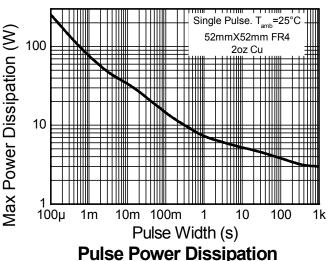


## **Thermal Characteristics and Derating Information**

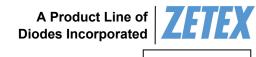












# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

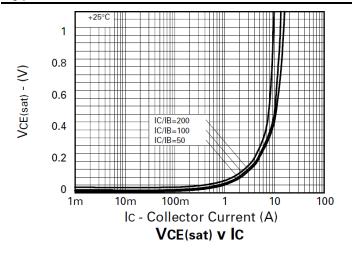
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50	85	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	50	85	_	V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage	BV <sub>CEV</sub>	50	85	_	V	I <sub>C</sub> = 100μA, V <sub>EB</sub> = 1V
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	17.5	24	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.7	_	V	I <sub>E</sub> = 100μA
Collector Cut-off Current	I <sub>CBO</sub>	_	0.3	10	nA	V <sub>CB</sub> = 35V
Collector Cut-off Current	I <sub>CES</sub>		0.3	10	nA	V <sub>CB</sub> = 35V
Emitter Cut-off Current	I <sub>EBO</sub>	_	0.3	10	nA	V <sub>EB</sub> = 4V
	,,	_	27	45	mV	I <sub>C</sub> = 500mA, I <sub>B</sub> = 10mA
Collector Emitter Seturation Voltage (Note 11)		_	55	75		I <sub>C</sub> = 1A, I <sub>B</sub> = 10mA
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	_	155	210		I <sub>C</sub> = 3A, I <sub>B</sub> = 15mA
		_	250	350		I <sub>C</sub> = 5A, I <sub>B</sub> = 25mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	_	920	1000	mV	I <sub>C</sub> = 5A, I <sub>B</sub> = 25mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	_	880	970	mV	I <sub>C</sub> = 5A, V <sub>CE</sub> = 2V
		290	440	1200		I <sub>C</sub> = 10mA, V <sub>CE</sub> = 2V
DC Compant Cair (Nata 44)		300	450	1200		I <sub>C</sub> = 1A, V <sub>CE</sub> = 2V
DC Current Gain (Note 11)	h <sub>FE</sub>	180	300	_	_	I <sub>C</sub> = 5A, V <sub>CE</sub> = 2V
		50	90	_		I <sub>C</sub> = 20A, V <sub>CE</sub> = 2V
Output Capacitance	C <sub>obo</sub>	_	60	80	pF	V <sub>CB</sub> = 10V, f = 1MHz
Current Gain-Bandwidth Product	f <sub>T</sub>	_	150	_	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 50MHz
Switching Times	t <sub>on</sub>	_	120	_	no	I <sub>C</sub> = 4A, V <sub>CC</sub> = 10V,
Switching Times	t <sub>off</sub>	_	310	_	ns	$I_{B1} = -I_{B2} = 40 \text{mA}$

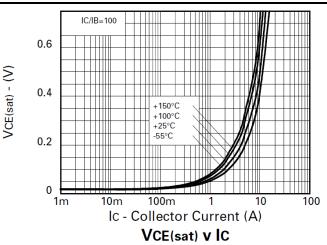
Note:

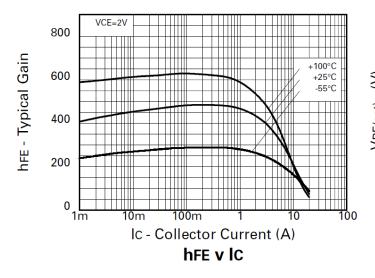
11. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2

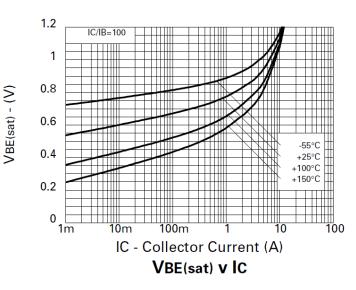


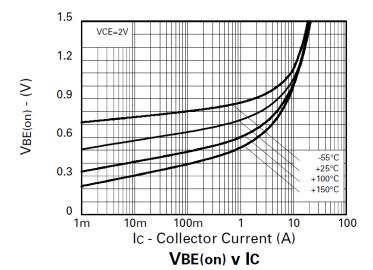
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







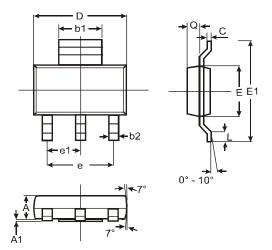






## **Package Outline Dimensions**

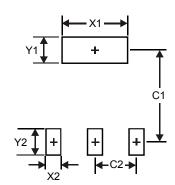
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b1	2.90	3.10	3.00		
b2	0.60	0.80	0.70		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	_		4.60		
e1	_		2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
X1	3.3		
X2	1.2		
Y1	1.6		
Y2	1.6		
C1	6.4		
C2	23		





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